

General Description

The 843001I-22 is a highly versatile, low phase noise LVPECL/LVCMOS Synthesizer which can generate low jitter reference clocks for a variety of communications applications and is a member of the family of high performance clock solutions from IDT. The dual crystal interface allows the synthesizer to support up to two communication standards in a given application (i.e. 1Gb Ethernet with a 25MHz crystal and 1Gb Fibre Channel using a 26.5625MHz crystal). The rms phase jitter performance is typically less than 1ps, thus making the device acceptable for use in demanding applications such as OC48 SONET and 10Gb Ethernet. The 843001I-22 is packaged in a small 24-pin TSSOP package.

Control Input Function Table

Input	Outputs	
OE	Q/nQ	REF_OUT
0	High-Impedance	High-Impedance
1	High-Impedance	Active
FLOAT	Active	High-Impedance

Features

- One 3.3V differential LVPECL output pair and one LVCMOS/LVTTL single-ended reference clock output
- Selectable crystal oscillator interface or LVCMOS/LVTTL single-ended input
- VCO range: 490MHz – 640MHz
- Output frequency range: 49MHz – 640MHz
- Supports the following applications: SONET, Ethernet, Fibre Channel, Serial ATA, and HDTV
- RMS phase jitter @ 125MHz (1.875MHz - 20MHz): 0.50ps (typical)
- Full 3.3V or 2.5V supply mode
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) package

Pin Assignment

VCCO_LVCMOS	1	24	REF_OUT
N0	2	23	VEE
N1	3	22	OE
N2	4	21	M2
VCCO_LVPECL	5	20	M1
Q	6	19	M0
nQ	7	18	MR
VEE	8	17	SEL1
VCCA	9	16	SELO
VCC	10	15	CLK
XTAL_OUT1	11	14	XTAL_IN0
XTAL_IN1	12	13	XTAL_OUT0

843001I-22

24-Lead TSSOP
4.4mm x 7.8mm x 0.925mm
package body
G Package
Top View

Block Diagram

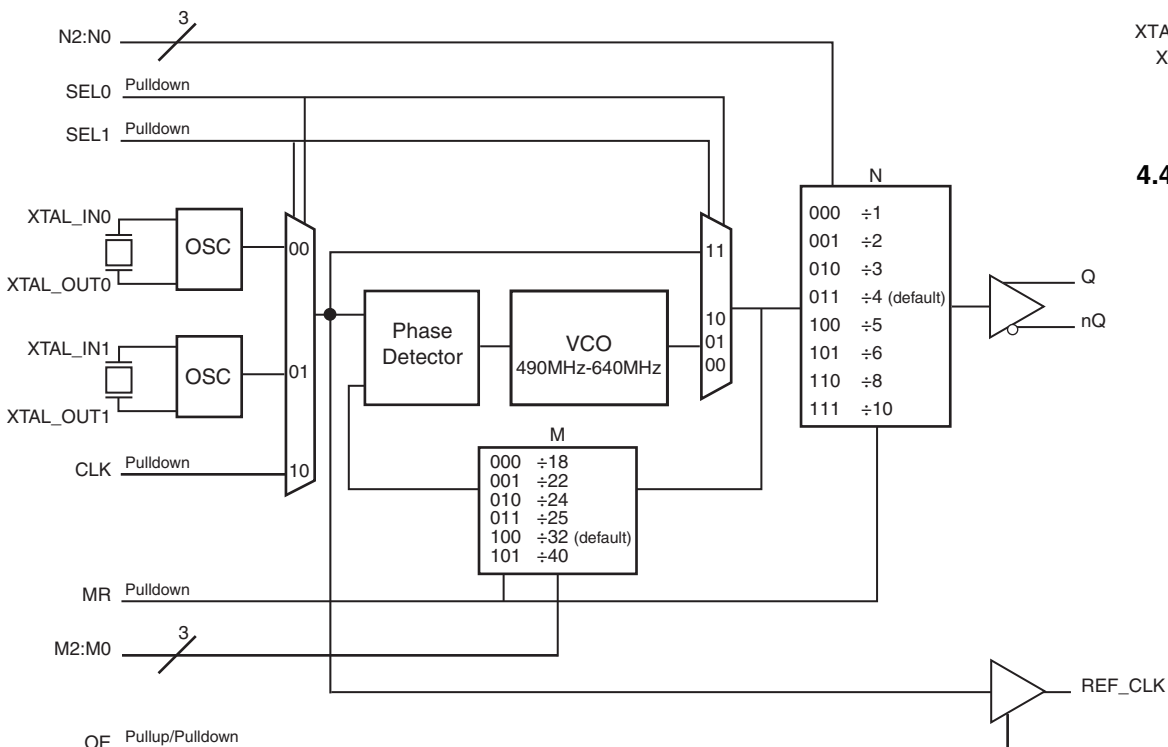


Table 1. Pin Descriptions

Number	Name	Type		Description
1	V _{CCO_LVCMOS}	Power		Output supply pin for REF_CLK output.
2, 3	N0, N1	Input	Pullup	Output divider select pins. Default ÷4. LVCMOS/LVTTL interface levels. See Table 3C.
4	N2	Input	Pulldown	
5	V _{CCO_LVPECL}	Power		Output supply pin for LVPECL output.
6, 7	Q, nQ	Output		Differential output pair. LVPECL interface levels.
8, 23	V _{EE}	Power		Negative supply pins.
9	V _{CCA}	Power		Analog supply pin.
10	V _{CC}	Power		Core supply pin.
11, 12	XTAL_OUT1, XTAL_IN1	Input		Parallel resonant crystal interface. XTAL_OUT1 is the output, XTAL_IN1 is the input.
13, 14	XTAL_OUT0, XTAL_IN0	Input		Parallel resonant crystal interface. XTAL_OUT0 is the output, XTAL_IN0 is the input.
15	CLK	Input	Pulldown	LVCMOS/LVTTL clock input.
16, 17	SEL0, SEL1	Input	Pulldown	Input MUX select pins. LVCMOS/LVTTL interface levels. See Table 3D.
18	MR	Input	Pulldown	Active HIGH Master Reset. When logic HIGH, the internal dividers are reset causing the true output Q to go low and the inverted output nQ to go high. When logic LOW, the internal dividers and the outputs are enabled. LVCMOS/LVTTL interface levels.
19, 20	M0, M1	Input	Pulldown	Feedback divider select pins. Default value = ÷32. See Table 3B. LVCMOS/LVTTL interface levels.
21	M2	Input	Pullup	
22	OE	Input		3-State clock output enable, (High/Low/Float). See page 1, <i>Control Input Function Table</i> .
24	REF_OUT	Output		Reference clock output. LVCMOS/LVTTL interface levels.

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
R _{PULLUP}	Input Pullup Resistor			51		kΩ
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ
R _{OUT}	Output Impedance	REF_OUT		15		Ω

Function Tables

Table 3A. Common Configuration Table

Input Reference Clock (MHz)	M Divider Value	N Divider Value	VCO (MHz)	Output Frequency (MHz)	Application
27	22	8	594	74.25	HDTV
22.4	25	8	560	70	
24.75	24	8	594	74.25	HDTV
25	24	3	600	200	Processor
14.8351649	40	8	593.4066	74.1758245	HDTV
19.44	32	4	622.08	155.52	SONET
19.44	32	8	622.08	77.76	SONET
19.44	32	1	622.08	622.08	SONET
19.44	32	2	622.08	311.04	SONET
19.53125	32	4	625	156.25	10 GigE
20	25	2	500	250	Ethernet
25	25	5	625	125	1 GigE
25	25	10	625	62.5	1 GigE
25	24	6	600	100	PCI Express
25	24	4	600	150	SATA
25	24	8	600	75	SATA
26.5625	24	6	637.5	106.25	Fibre Channel 1
26.5625	24	3	637.5	212.5	4 Gig Fibre Channel
26.5625	24	4	637.5	159.375	10 Gig Fibre Channel
31.25	18	3	562.5	187.5	12 GigE

Table 3B. Programmable M Output Divider Function Table

Inputs			M Divider Value	Input Frequency (MHz)	
M2	M1	M0		Minimum	Maximum
0	0	0	18	27.22	35.56
0	0	1	22	22.27	29.09
0	1	0	24	20.41	26.67
0	1	1	25	19.6	25.6
1	0	0	32	15.31	20
1	0	1	40	12.25	16

Table 3C. Programmable N Output Divider Function Table

Inputs			M Divider Value
N2	N1	N0	
0	0	0	1
0	0	1	2
0	1	0	3
0	1	1	4 (default)
1	0	0	5
1	0	1	6
1	1	0	8
1	1	1	10

Table 3D. Bypass Mode Function Table

Inputs		Reference	PLL Mode
SEL1	SEL0		
0	0	XTAL0	Active
0	1	XTAL1	Active
1	0	CLK	Active
1	1	CLK	Bypass

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{CC}	4.6V
Inputs, V_I	-0.5V to $V_{CC} + 0.5V$
Outputs, I_O (LVPECL) Continuous Current Surge Current	50mA 100mA
Outputs, V_O (LVCMOS)	-0.5V to $V_{CCO_LVCMOS} + 0.5V$
Package Thermal Impedance, θ_{JA}	70°C/W (0 mps)
Storage Temperature, T_{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{CC} = V_{CCO_LVCMOS} = V_{CCO_LVPECL} = 3.3V \pm 10\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{CC}	Core Supply Voltage		2.97	3.3	3.63	V
V_{CCA}	Analog Supply Voltage		2.97	3.3	3.63	V
V_{CCO_PECL} , V_{CCO_CMOS}	Output Supply Voltage		2.97	3.3	3.63	V
I_{EE}	Power Supply Current				160	mA
$I_{CCO_LVPECL} +$ I_{CCO_LVCMOS}	Output Supply Current				8	mA

Table 4B. Power Supply DC Characteristics, $V_{CC} = V_{CCO_LVCMOS} = V_{CCO_LVPECL} = 2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{CC}	Core Supply Voltage		2.375	2.5	2.625	V
V_{CCA}	Analog Supply Voltage		2.375	2.5	2.625	V
V_{CCO_PECL} , V_{CCO_CMOS}	Output Supply Voltage		2.375	2.5	2.625	V
I_{EE}	Power Supply Current				155	mA
$I_{CCO_LVPECL} +$ I_{CCO_LVCMOS}	Output Supply Current				8	mA

Table 4C. LVCMOS/LVTTL DC Characteristics, $V_{CC} = V_{CCO_LVCMOS} = 3.3V \pm 10\%$ or $2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{IH}	Input High Voltage	V _{CC} = 3.63V	2		V _{CC} + 0.3	V
		V _{CC} = 2.625V	1.7		V _{CC} + 0.3	V
V _{IM}	Input Medium Voltage	V _{CC} = 3.63V				V
		V _{CC} = 2.625V				V
V _{IL}	Input Low Voltage	V _{CC} = 3.63V	-0.3		0.8	V
		V _{CC} = 2.625V	-0.3		0.7	V
I _{IH}	Input High Current	CLK, M0, M1, N2, MR, OE, SEL0, SEL1	V _{CC} = V _{IN} = 3.63V or 2.625V		150	μA
		M2, N0, N1	V _{CC} = V _{IN} = 3.63V or 2.625V		5	μA
I _{IM}	Input Medium Current					μA
I _{IL}	Input Low Current	CLK, M0, M1, N2, MR, OE, SEL0, SEL1	V _{CC} = 3.63V or 2.625V, V _{IN} = 0V	-5		μA
		M2, N0, N1, OE	V _{CC} = 3.63V or 2.625V, V _{IN} = 0V	-150		μA
V _{OH}	Output High Voltage: NOTE 1	REF_OUT	V _{CCO_LVCMOS} = 3.63V	2.6		V
			V _{CCO_LVCMOS} = 2.625V	1.8		V
V _{OL}	Output Low Voltage: NOTE 1	REF_OUT	V _{CCO_LVCMOS} = 3.63V or 2.625V		0.5	V

NOTE 1: Output terminated with 50Ω to V_{CCO_LVCMOS}/2. See Parameter Measurement Information Section, "3.3V LVCMOS Output Load Test Circuit Diagram".

Table 4D. LVPECL DC Characteristics, $V_{CC} = V_{CCO_LVPECL} = 3.3V \pm 10\%$ or $2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{OH}	Output High Current; NOTE 1		V _{CCO} - 1.4		V _{CCO} - 0.9	μA
V _{OL}	Output Low Current; NOTE 1		V _{CCO} - 2.0		V _{CCO} - 1.7	μA
V _{SWING}	Peak-to-Peak Output Voltage Swing		0.6		1.0	V

NOTE 1: Outputs termination with 50Ω to V_{CCO_LVPECL} - 2V.

Table 5. Crystal Characteristics

Parameter	Test Conditions	Minimum	Typical	Maximum	Units
Mode of Oscillation		Fundamental			
Frequency		14		35.55	MHz
Equivalent Series Resistance (ESR)				50	Ω
Shunt Capacitance				7	pF
Drive Level				1	mW

NOTE: Characterized using an 18pF parallel resonant crystal.

Table 6. Input Frequency Characteristics, $V_{CC} = V_{CCO_LVCMOS} = V_{CCO_LVPECL} = 3.3V \pm 10\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{IN}	Input Frequency	CLK	SEL1 = 1, SEL0 = 0	14	35.55	MHz
		CLK	SEL1 = 1, SEL0 = 0	DC	250	MHz

AC Electrical Characteristics

Table 7A. AC Characteristics, $V_{CC} = V_{CCO_LVCMOS} = V_{CCO_LVPECL} = 3.3V \pm 10\%$, $V_{EE} = 0V$, $T_A = -40^\circ C$ to $85^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency		49		640	MHz
$f_{jit}(\emptyset)$	RMS Phase Jitter, (Random); NOTE 1	125MHz, (1.875MHz – 20MHz)		0.50		ps
f_{VCO}	PLL VCO Lock Range		490		640	MHz
t_R / t_F	Output Rise/Fall Time	Q/nQ	20% to 80%	200	500	ps
		REF_OUT	20% to 80%	200	700	ps
odc	Output Duty Cycle	Q/nQ		45	55	%
		REF_OUT	$f \leq 250\text{MHz}$	44	56	%

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Phase jitter measured using a crystal interface.

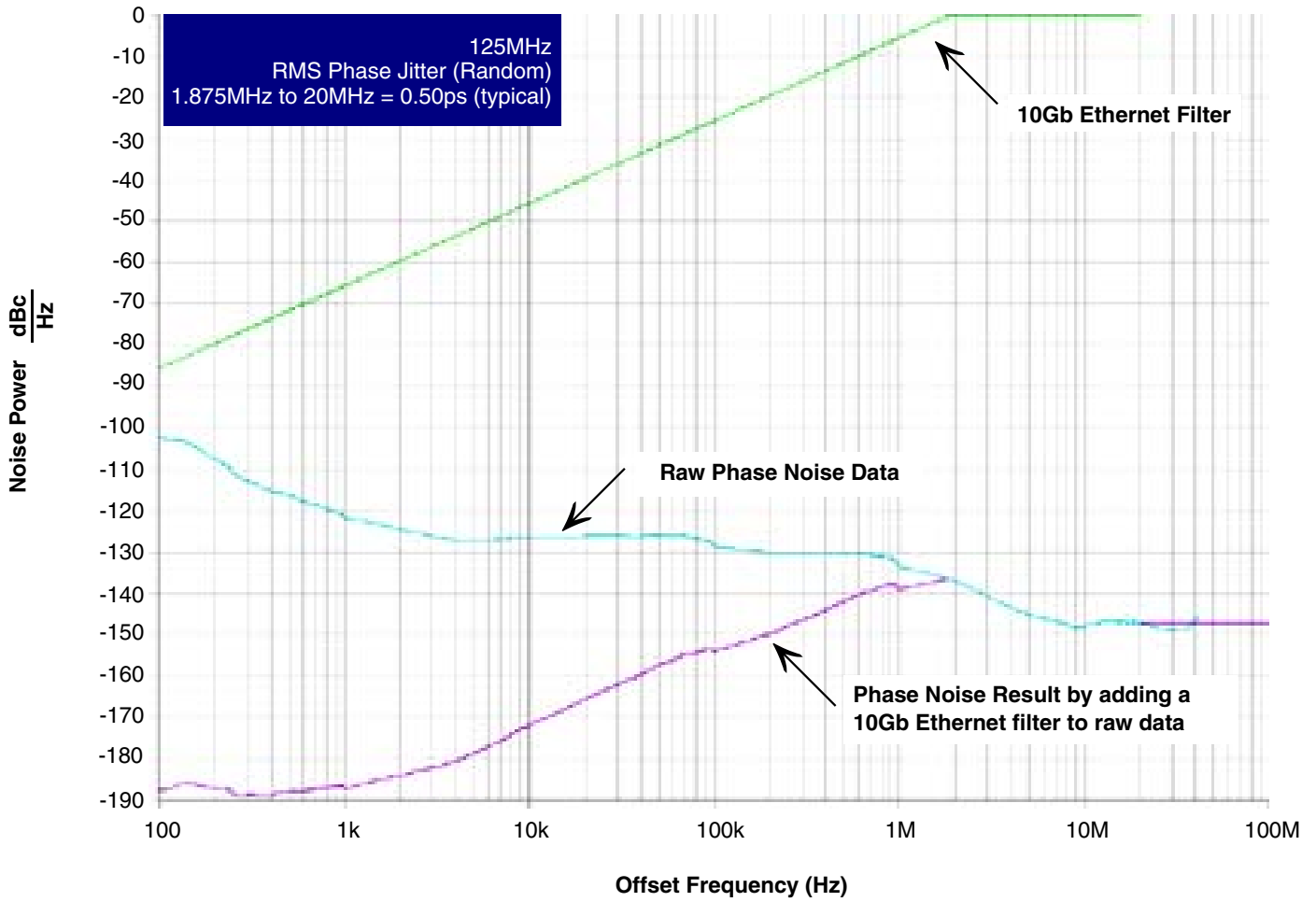
Table 7B. AC Characteristics, $V_{CC} = V_{CCO_LVCMOS} = V_{CCO_LVPECL} = 2.5V \pm 5\%$, $V_{EE} = 0V$, $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency		49		640	MHz
$\text{jit}(\emptyset)$	RMS Phase Jitter, (Random); NOTE 1	125MHz, (1.875MHz – 20MHz)		0.50		ps
f_{VCO}	PLL VCO Lock Range		490		640	MHz
t_R / t_F	Output Rise/Fall Time	Q/nQ	20% to 80%	200	500	ps
		REF_OUT	20% to 80%	300	800	ps
odc	Output Duty Cycle	Q/nQ		45	55	%
		REF_OUT	$f \leq 250\text{MHz}$	44	56	%

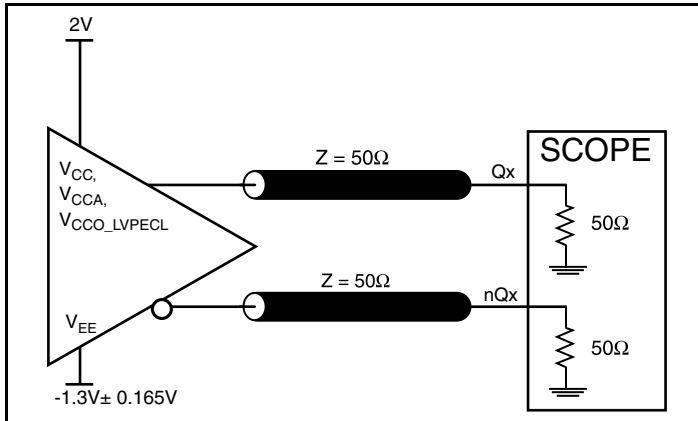
NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Phase jitter measured using a crystal interface.

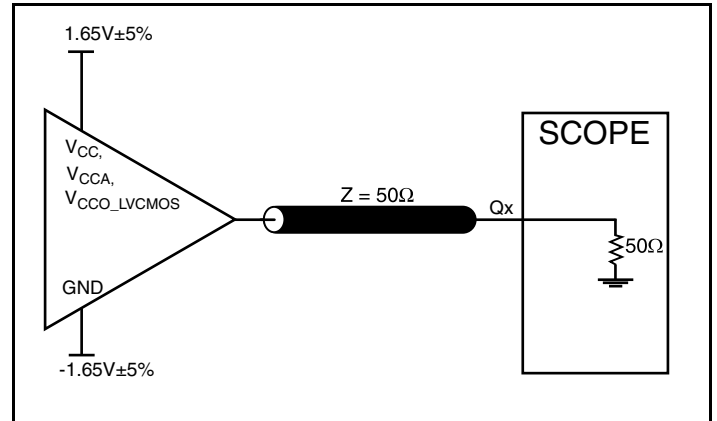
Typical Phase Noise at 125MHz



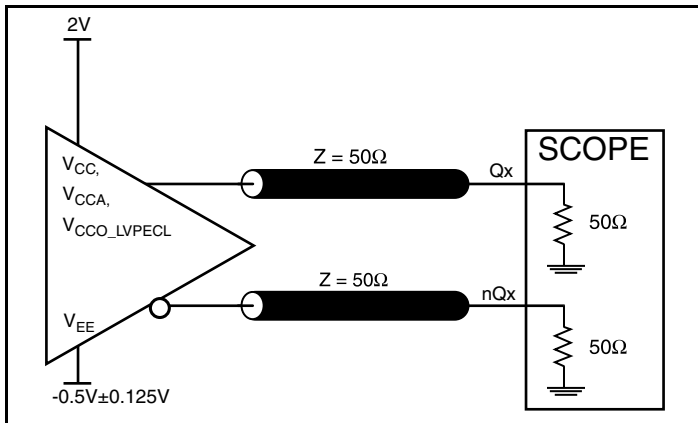
Parameter Measurement Information



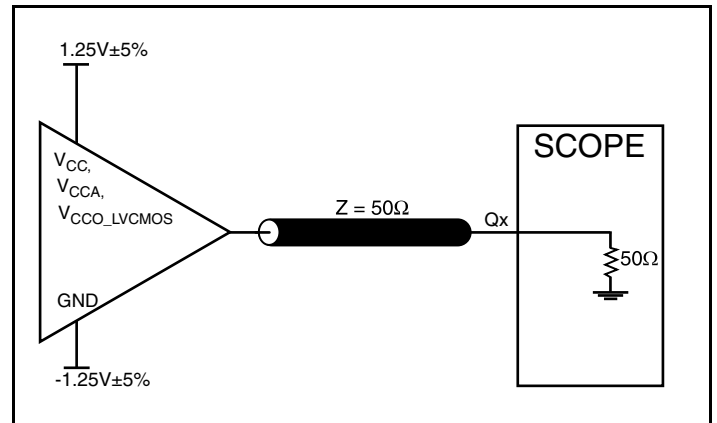
3.3V LVPECL Output Load AC Test Circuit



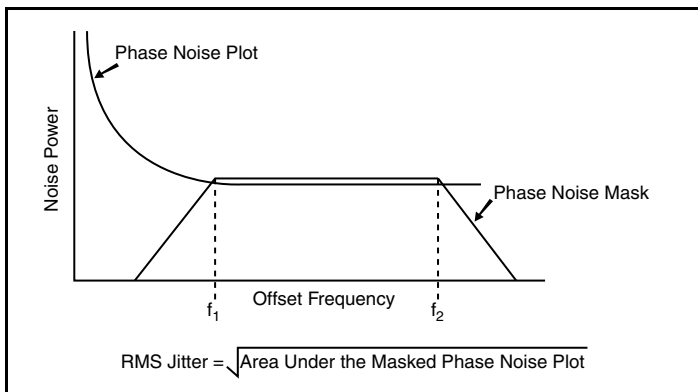
3.3V LVCMOS Output Load AC Test Circuit



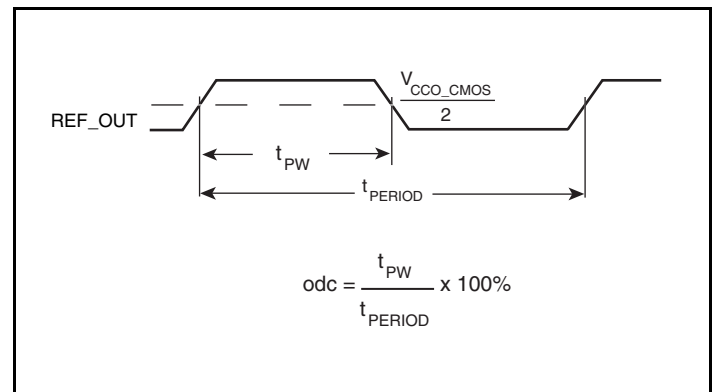
2.5V LVPECL Output Load AC Test Circuit



2.5V LVCMOS Output Load AC Test Circuit

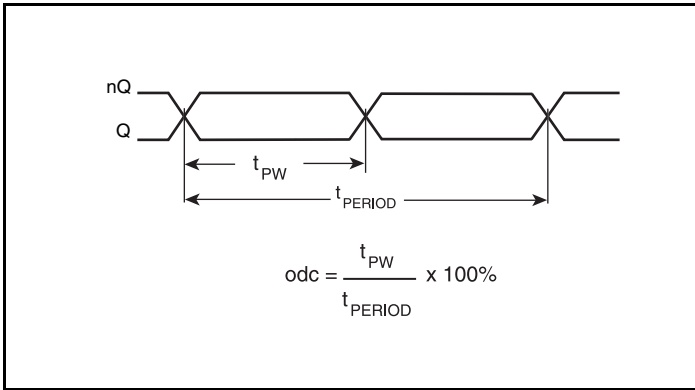


RMS Phase Jitter

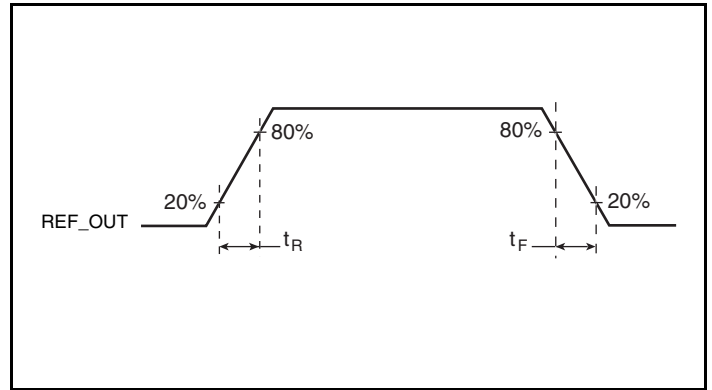


LVCMOS Output Duty Cycle/Pulse Width/Period

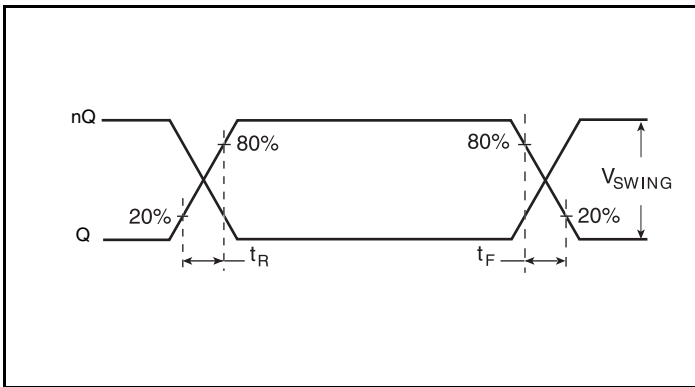
Parameter Measurement Information, continued



LVPECL Output Duty Cycle/Pulse Width/Period



LVCMOS Output Rise/Fall Time



LVPECL Output Rise/Fall Time

Application Information

Power Supply Filtering Technique

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The 8430011-22 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{CC} , V_{CCA} , V_{CCO_X} should be individually connected to the power supply plane through vias, and $0.01\mu F$ bypass capacitors should be used for each pin. *Figure 1* illustrates this for a generic V_{CC} pin and also shows that V_{CCA} requires that an additional 10Ω resistor along with a $10\mu F$ bypass capacitor be connected to the V_{CCA} pin.

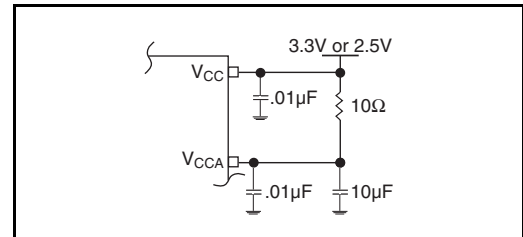


Figure 1. Power Supply Filtering

Crystal Input Interface

The 843001I-22 has been characterized with 18pF parallel resonant crystals. The capacitor values shown in *Figure 2* below were

determined using a 26.5625MHz, 18pF parallel resonant crystal and were chosen to minimize the ppm error.

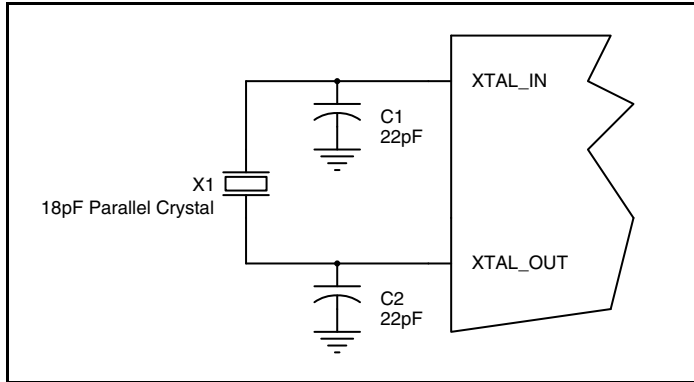


Figure 2. Crystal Input Interface

LVC MOS to XTAL Interface

The XTAL_IN input can accept a single-ended LVC MOS signal through an AC coupling capacitor. A general interface diagram is shown in *Figure 3*. The XTAL_OUT pin can be left floating. The input edge rate can be as slow as 10ns. For LVC MOS signals, it is recommended that the amplitude be reduced from full swing to half swing in order to prevent signal interference with the power rail and to reduce noise. This configuration requires that the output impedance of the driver (R_o) plus the series resistance (R_s) equals

the transmission line impedance. In addition, matched termination at the crystal input will attenuate the signal in half. This can be done in one of two ways. First, R_1 and R_2 in parallel should equal the transmission line impedance. For most 50Ω applications, R_1 and R_2 can be 100Ω. This can also be accomplished by removing R_1 and making R_2 50Ω. By overdriving the crystal oscillator, the device will be functional, but note, the device performance is guaranteed by using a quartz crystal.

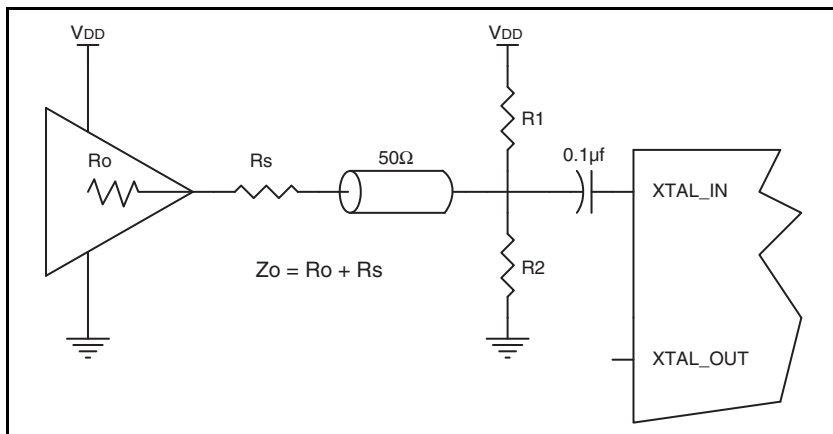


Figure 3. General Diagram for LVC MOS Driver to XTAL Input Interface

Recommendations for Unused Input and Output Pins

Inputs:

Crystal Inputs

For applications not requiring the use of the crystal oscillator input, both XTAL_IN and XTAL_OUT can be left floating. Though not required, but for additional protection, a 1kΩ resistor can be tied from XTAL_IN to ground.

CLK Input

For applications not requiring the use of the clock input, it can be left floating. Though not required, but for additional protection, a 1kΩ resistor can be tied from the CLK input to ground.

LVC MOS Control Pins

All control pins have internal pullups or pulldowns; additional resistance is not required but can be added for additional protection. A 1kΩ resistor can be used.

Outputs:

LVPECL Outputs

The unused LVPECL output pair can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.

LVC MOS Output

All unused LVC MOS output can be left floating. We recommend that there is no trace attached.

Termination for 3.3V LVPECL Outputs

The clock layout topology shown below is a typical termination for LVPECL outputs. The two different layouts mentioned are recommended only as guidelines.

The differential outputs are low impedance follower outputs that generate ECL/LVPECL compatible outputs. Therefore, terminating resistors (DC current path to ground) or current sources must be used for functionality. These outputs are designed to drive 50Ω

transmission lines. Matched impedance techniques should be used to maximize operating frequency and minimize signal distortion. *Figures 4A and 4B* show two different layouts which are recommended only as guidelines. Other suitable clock layouts may exist and it would be recommended that the board designers simulate to guarantee compatibility across all printed circuit and clock component process variations.

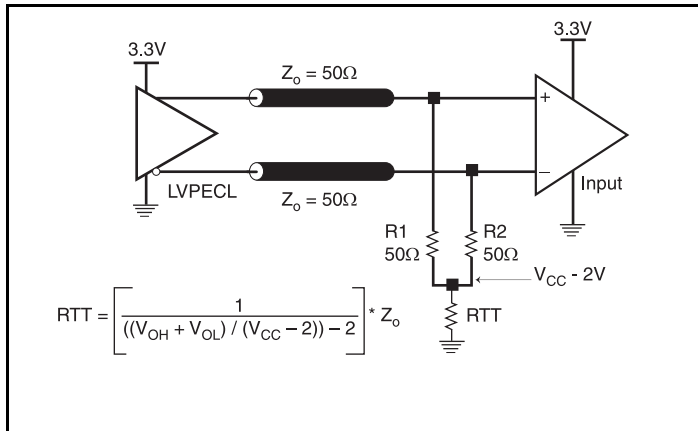


Figure 4A. 3.3V LVPECL Output Termination

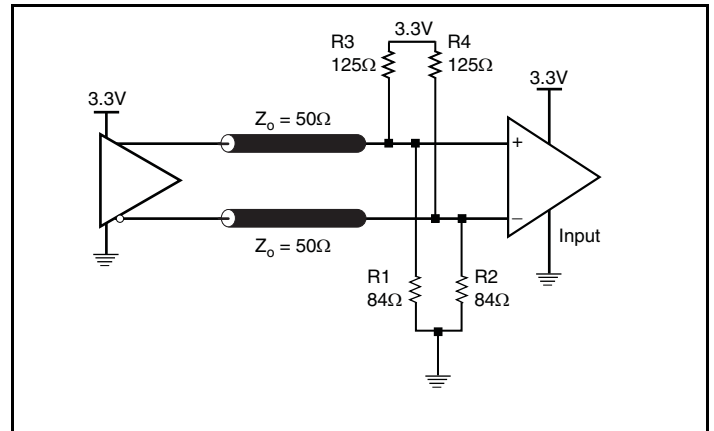


Figure 4B. 3.3V LVPECL Output Termination

Termination for 2.5V LVPECL Outputs

Figure 5A and Figure 5B show examples of termination for 2.5V LVPECL driver. These terminations are equivalent to terminating 50Ω to $V_{CC} - 2V$. For $V_{CC} = 2.5V$, the $V_{CC} - 2V$ is very close to ground

level. The R3 in Figure 5B can be eliminated and the termination is shown in Figure 5C.

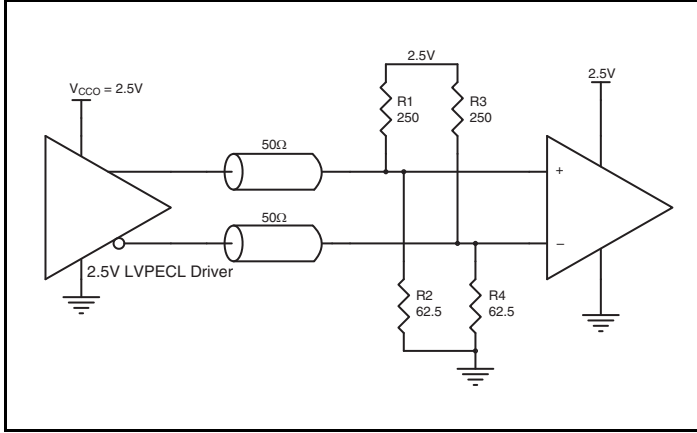


Figure 5A. 2.5V LVPECL Driver Termination Example

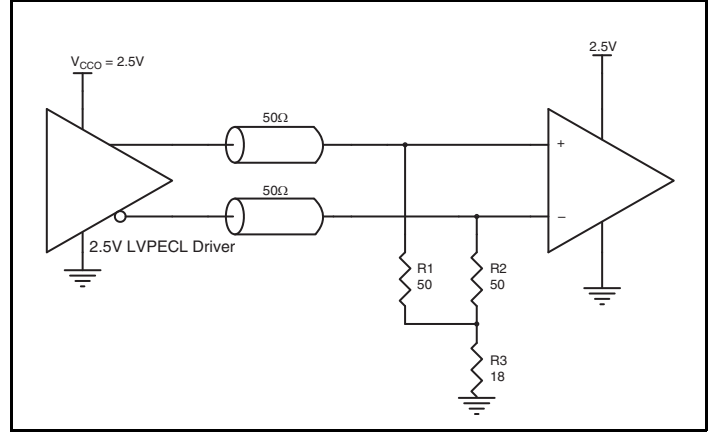


Figure 5B. 2.5V LVPECL Driver Termination Example

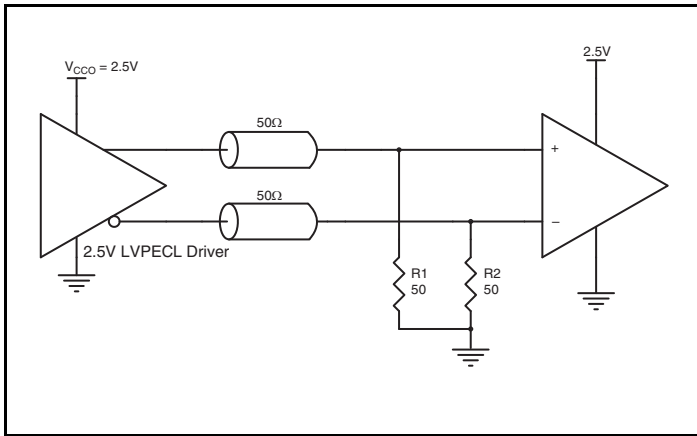
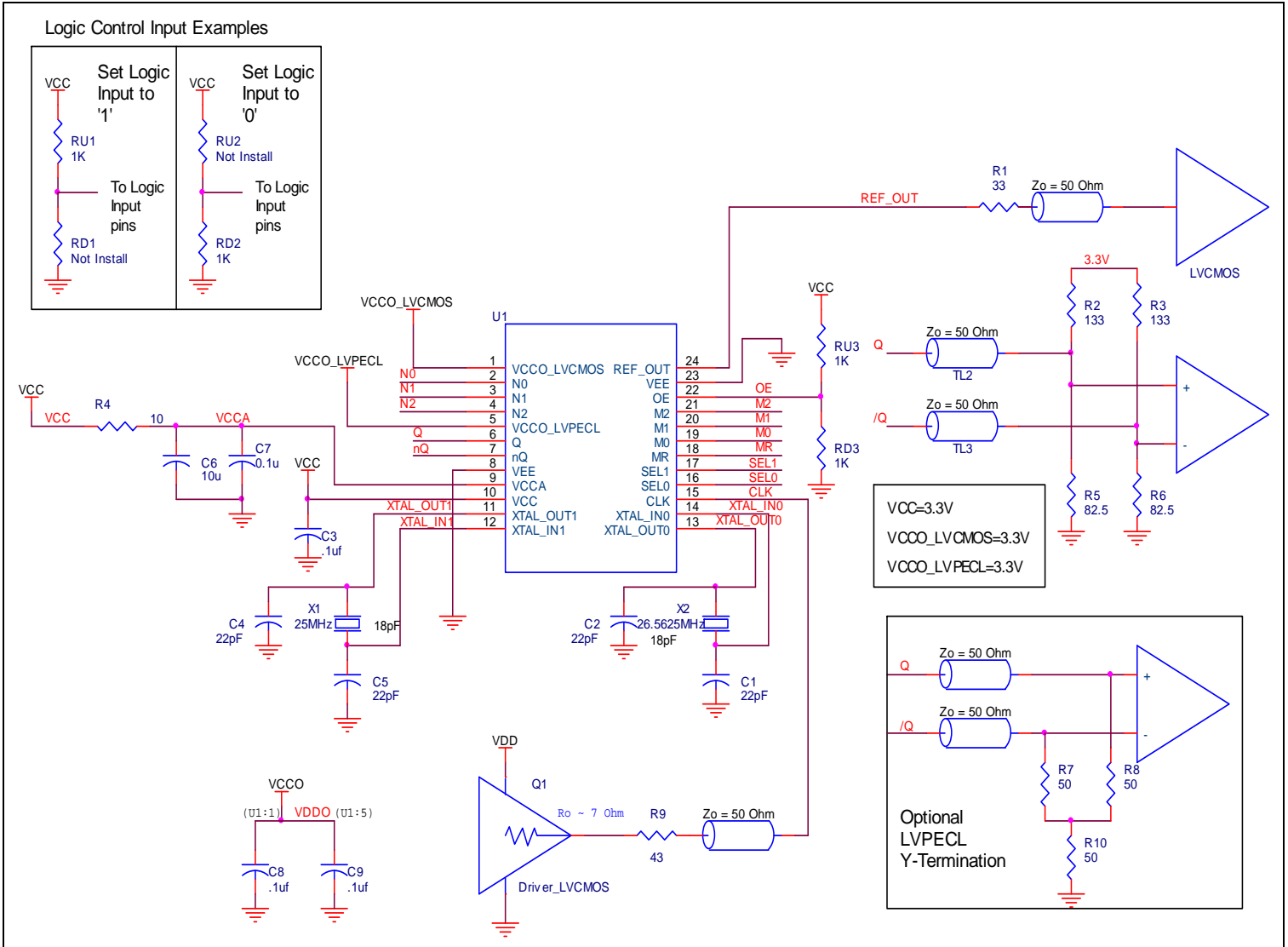


Figure 5C. 2.5V LVPECL Driver Termination Example

Schematic Layout

Figure 6 shows an example of 8430011-22 application schematic. In this example, the device is operated at $V_{CC} = V_{CCO_LVCMOS} = V_{CCO_LVPECL} = 3.3V$. The 18pF parallel resonant 25MHz crystal is used. The $C1 = C2 = 22pF$ and $C4 = C5 = 22pF$ are recommended for frequency accuracy. For different board layouts, the $C1, C2, C4$

and $C5$ may be slightly adjusted for optimizing frequency accuracy. Two examples of LVPECL terminations and one example of LVCMOS are shown in this schematic. Additional termination approaches are shown in the LVPECL Termination Application Note.



8430011-22 Layout Example

Power Considerations

This section provides information on power dissipation and junction temperature for the 8430011-22. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the 8430011-22 is the sum of the core power plus the power dissipated in the load(s). The following is the power dissipation for $V_{CC} = 3.3V + 5\% = 3.465V$, which gives worst case results.

NOTE: Please refer to Section 3 for details on calculating power dissipated in the load.

- Power (core)_{MAX} = $V_{CC_MAX} * I_{EE_MAX} = 3.465V * 160mA = 554.4mW$
- Power (outputs)_{MAX} = **30mW/Loaded Output pair**

Total Power_{MAX} (3.3V, with all outputs switching) = $554.4mW + 30mW = 584.4mW$

2. Junction Temperature.

Junction temperature, T_j , is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature for HiPerClockS devices is 125°C.

The equation for T_j is as follows: $T_j = \theta_{JA} * Pd_total + T_A$

T_j = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming a moderate air flow of 1 meter per second and a multi-layer board, the appropriate value is 65°C/W per Table 8 below.

Therefore, T_j for an ambient temperature of 85°C with all outputs switching is:

$$85^\circ C + 0.584W * 65^\circ C/W = 123^\circ C. \text{ This is below the limit of } 125^\circ C.$$

This calculation is only an example. T_j will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (single layer or multi-layer).

Table 8. Thermal Resistance θ_{JA} for 24 Lead TSSOP, Forced Convection

θ_{JA} vs. Air Flow			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	70°C/W	65°C/W	62°C/W

3. Calculations and Equations.

The purpose of this section is to derive the power dissipated into the load.

LVPECL output driver circuit and termination are shown in *Figure 7*.

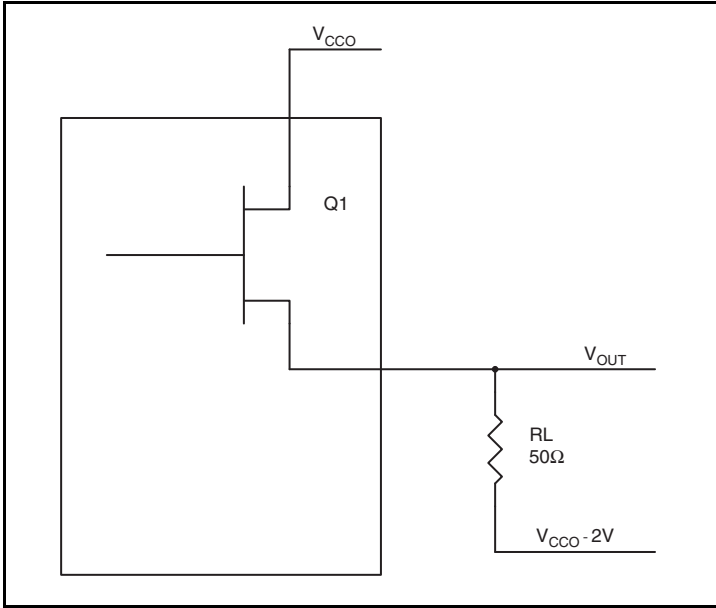


Figure 7. LVPECL Driver Circuit and Termination

To calculate worst case power dissipation into the load, use the following equations which assume a 50Ω load, and a termination voltage of V_{CCO} - 2V.

- For logic high, V_{OUT} = V_{OH_MAX} = V_{CCO_MAX} - 0.9V
(V_{CCO_MAX} - V_{OH_MAX}) = 0.9V
- For logic low, V_{OUT} = V_{OL_MAX} = V_{CCO_MAX} - 1.7V
(V_{CCO_MAX} - V_{OL_MAX}) = 1.7V

Pd_H is power dissipation when the output drives high.

Pd_L is the power dissipation when the output drives low.

$$Pd_H = [(V_{OH_MAX} - (V_{CCO_MAX} - 2V))/R_L] * (V_{CCO_MAX} - V_{OH_MAX}) = [(2V - (V_{CCO_MAX} - V_{OH_MAX}))/R_L] * (V_{CCO_MAX} - V_{OH_MAX}) = [(2V - 0.9V)/50\Omega] * 0.9V = \mathbf{19.8mW}$$

$$Pd_L = [(V_{OL_MAX} - (V_{CCO_MAX} - 2V))/R_L] * (V_{CCO_MAX} - V_{OL_MAX}) = [(2V - (V_{CCO_MAX} - V_{OL_MAX}))/R_L] * (V_{CCO_MAX} - V_{OL_MAX}) = [(2V - 1.7V)/50\Omega] * 1.7V = \mathbf{10.2mW}$$

$$\text{Total Power Dissipation per output pair} = Pd_H + Pd_L = \mathbf{30mW}$$

Reliability Information

Table 9. θ_{JA} vs. Air Flow Table for a 24 Lead TSSOP

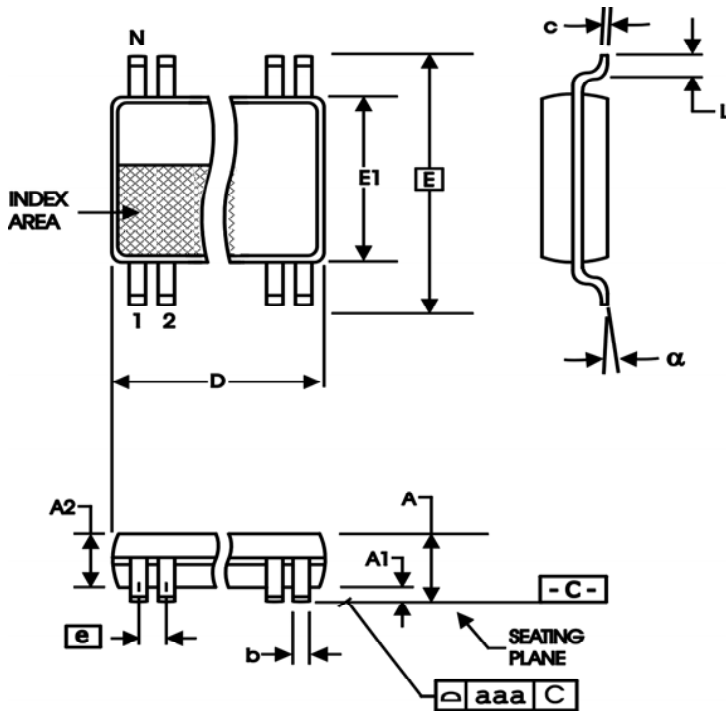
θ_{JA} vs. Air Flow			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	70°C/W	65°C/W	62°C/W

Transistor Count

The transistor count for 843001I-22 is: 3881

Package Outline and Package Dimensions

Package Outline - G Suffix for 24 Lead TSSOP



6.10 mm. Body, 0.65 mm. Pitch TSSOP
(240 mil)* (25.6mil)*

Table 10. Package Dimensions

All Dimensions in Millimeters		
Symbol	Minimum	Maximum
N	24	
A		1.20
A1	0.5	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	7.70	7.90
E	6.40 Basic	
E1	4.30	4.50
e	0.65 Basic	
L	0.45	0.75
α	0°	8°
aaa		0.10

Reference Document: JEDEC Publication 95, MO-153

Ordering Information

Table 11. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
843001AGI-22LF	ICS43001AI22L	"Lead-Free" 24 Lead TSSOP	Tube	-40°C to 85°C
843001AGI-22LFT	ICS43001AI22L	"Lead-Free" 24 Lead TSSOP	2500 Tape & Reel	-40°C to 85°C

NOTE: "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

Revision History Sheet

Rev	Table	Page	Description of Change	Date
A		1	General Description - corrected crystal frequency from 25.5625MHz crystal to 26.5625MHz crystal.	3/23/07
		12	Added <i>LVC MOS to XTAL Interface</i> section. Updated format throughout the datasheet.	
A	T11	16	Power Considerations - Changed Ambient Temperature from 70° to 85°	2/19/09
		19	Ordering Information - Removed "ICS" from Part/Order Number	
B		1	Corrected block diagram. When updated format on 3/23/07, block diagram was not duplicated correctly.	6/25/09
		15	Added Schematic layout. Updated header/footer.	
B	T11	19	Removed leaded orderable parts from Ordering Information table	11/14/12
B			Updated data sheet format.	11/16/15

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Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu,
Koto-ku, Tokyo 135-0061, Japan
www.renesas.com

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